

## isc Silicon PNP Power Transistor

# 2SB954

### DESCRIPTION

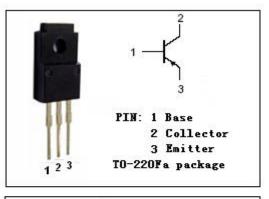
- Low Collector Saturation Voltage-
  - : V<sub>CE(sat)</sub>= -1.0V(Max)@I<sub>C</sub>= -1A
- Good Linearity of  $h_{\text{FE}}$
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

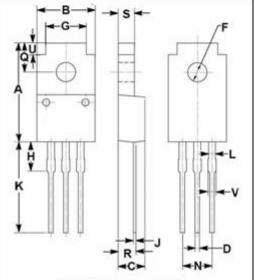
### **APPLICATIONS**

• Designed for power amplifications.

### ABSOLUTE MAXIMUM RATINGS(Ta=25 °C)

SYMBOL	PARAMETER	VALUE	UNIT
V <sub>СВО</sub>	Collector-Base Voltage	-60	V
V <sub>CEO</sub>	Collector-Emitter Voltage	-60	V
V <sub>EBO</sub>	Emitter-Base Voltage	-5	V
lc	Collector Current-Continuous	-1	А
I <sub>CM</sub>	Collector Current-Peak	-2	А
Pc	Collector Power Dissipation @ T <sub>a</sub> =25°C	2	W
	Collector Power Dissipation @ T <sub>c</sub> =25°C	30	VV
TJ	Junction Temperature	150	°C
T <sub>stg</sub>	Storage Temperature Range	-55~150	°C





	mm	
DIM	MIN	MAX
A	16.85	17.15
В	9.54	10.10
C	4.35	4.65
D	0.75	0.90
F	3.20	3.40
G	6.90	7.20
H	5.15	5.45
J	0.45	0.75
ĸ	13.35	13.65
L	1.10	1.30
N	4.98	5.18
Q	4.85	5.15
R	2.55	3.25
S	2.70	2.90
U	1.75	2.05
V	1.30	1.50

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### **ELECTRICAL CHARACTERISTICS**

#### $T_c=25^{\circ}C$ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	МАХ	UNIT
V <sub>(BR)CEO</sub>	Collector-Emitter Breakdown Voltage	Ic= -30mA; I <sub>B</sub> = 0	-60			V
V <sub>CE(sat)</sub>	Collector-Emitter Saturation Voltage	I <sub>C</sub> = -1A; I <sub>B</sub> = -0.125A			-1.0	V
V <sub>BE(on)</sub>	Base-Emitter On Voltage	I <sub>C</sub> = -1A; V <sub>CE</sub> = -4V			-1.3	V
I <sub>CEO</sub>	Collector Cutoff Current	V <sub>CE</sub> = -30V; I <sub>B</sub> = 0			-300	μA
I <sub>CES</sub>	Collector Cutoff Current	V <sub>CE</sub> = -60V; V <sub>BE</sub> = 0			-200	μA
Іево	Emitter Cutoff Current	V <sub>EB</sub> = -5V; I <sub>C</sub> = 0			-1	mA
h <sub>FE-1</sub>	DC Current Gain	I <sub>C</sub> = -0.2A; V <sub>CE</sub> = -4V	70		250	
h <sub>FE-2</sub>	DC Current Gain	I <sub>C</sub> = -1A; V <sub>CE</sub> = -4V	15			

### h<sub>FE-1</sub> Classifications

Q	Р		
70-150	120-250		

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